

FEATURES

- ZENER VOLTAGE 12.8V
- TEMPERATURE COEFFICIENT RANGE: 0.01%/°C to 0.001%/°C
- N_D YIELDS MAXIMUM-RMS NOISE FOR ANY BANDWIDTH

MAXIMUM RATINGS

Junction and Storage Temperatures: -65°C to +175°C
DC Power Dissipation: 400 mW
Power Derating: 3.20 mW/°C above 50°C

*** ELECTRICAL CHARACTERISTICS**

@ 25°C, unless otherwise specified

JEDEC TYPE NUMBER	TEST CURRENT I _{ZT}	MAX. VOLTAGE CHANGE WITH TEMPERATURE ΔV _{ZT}	TEMPERATURE RANGE °C	EFFECTIVE TEMPERATURE COEFFICIENT α _{VZ}	MAXIMUM DYNAMIC IMPEDANCE Z _{DT}	MAXIMUM NOISE DENSITY N _D
	(Note 1 & 5)	(Note 2 & 5)		(Note 3)	(Note 4)	
	mA	VOLTS		± %/°C	OHMS	μV/V cps
1N4896	0.5	0.096	+25 to +100	0.01	400	0.8
1N4896A	0.5	0.198	-55 to +100	0.01	400	0.8
1N4897	0.5	0.048	+25 to +100	0.005	400	0.8
1N4897A	0.5	0.099	-55 to +100	0.005	400	0.8
1N4898	0.5	0.019	+25 to +100	0.002	400	0.8
1N4898A	0.5	0.040	-55 to +100	0.002	400	0.8
1N4899	0.5	0.010	+25 to +100	0.001	400	0.8
1N4899A	0.5	0.020	-55 to +100	0.001	400	0.8
1N4900	1.0	0.096	+25 to +100	0.01	200	0.4
1N4900A	1.0	0.198	-55 to +100	0.01	200	0.4
1N4901	1.0	0.048	+25 to +100	0.005	200	0.4
1N4901A	1.0	0.099	-55 to +100	0.005	200	0.4
1N4902	1.0	0.019	+25 to +100	0.002	200	0.4
1N4902A	1.0	0.040	-55 to +100	0.002	200	0.4
1N4903	1.0	0.010	+25 to +100	0.001	200	0.4
1N4903A	1.0	0.020	-55 to +100	0.001	200	0.4
1N4904	2.0	0.096	+25 to +100	0.01	100	0.25
1N4904A	2.0	0.198	-55 to +100	0.01	100	0.25
1N4905	2.0	0.048	+25 to +100	0.005	100	0.25
1N4905A	2.0	0.099	-55 to +100	0.005	100	0.25
1N4906	2.0	0.019	+25 to +100	0.002	100	0.25
1N4906A	2.0	0.040	-55 to +100	0.002	100	0.25
1N4907	2.0	0.010	+25 to +100	0.001	100	0.25
1N4907A	2.0	0.020	-55 to +100	0.001	100	0.25
1N4908	4.0	0.096	+25 to +100	0.01	50	0.22
1N4908A	4.0	0.198	-55 to +100	0.01	50	0.22
1N4909	4.0	0.048	+25 to +100	0.005	50	0.22
1N4909A	4.0	0.099	-55 to +100	0.005	50	0.22
1N4910	4.0	0.019	+25 to +100	0.002	50	0.22
1N4910A	4.0	0.040	-55 to +100	0.002	50	0.22
1N4911	4.0	0.010	+25 to +100	0.001	50	0.22
1N4911A	4.0	0.020	-55 to +100	0.001	50	0.22
1N4912	7.5	0.096	+25 to +100	0.01	25	0.20
1N4912A	7.5	0.198	-55 to +100	0.01	25	0.20
1N4913	7.5	0.048	+25 to +100	0.005	25	0.20
1N4913A	7.5	0.099	-55 to +100	0.005	25	0.20
1N4914	7.5	0.019	+25 to +100	0.002	25	0.20
1N4914A	7.5	0.040	-55 to +100	0.002	25	0.20
1N4915	7.5	0.010	+25 to +100	0.001	25	0.20
1N4915A	7.5	0.020	-55 to +100	0.001	25	0.20

**12.8 VOLT LOW NOISE
TEMPERATURE
COMPENSATED
ZENER REFERENCE
DIODES**

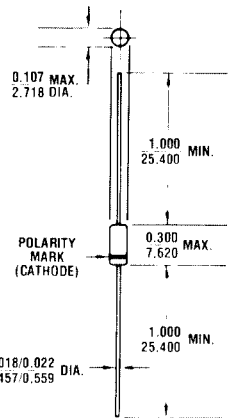


FIGURE 1

All dimensions in INCH
m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N4896 thru 1N4915A

NOTE 1 Nominal voltage for all types is 12.8 Volts $\pm 5\%$.

NOTE 2 Referred to as the 'box' measurement method, the ΔV_{ZT} is the maximum voltage variance that will occur as the voltage is scanned thru all temperatures between the temperature range limits.

NOTE 3 The effective temperature coefficients are tabulated in $\%/^{\circ}\text{C}$ primarily for information only since temperature compensated diodes inherently have a non-linear voltage-temperature characteristic.

NOTE 4 The dynamic Zener impedance Z_{ZT} is derived from the resulting a.c. voltage developed when a 60 cps, rms a.c. current equal to 10% of the D.C. Zener current I_{ZT} is superimposed on I_{ZT}

NOTE 5 Voltage measurements to be performed 15 seconds after application of DC current.

NOTE 6 To specify radiation hardened devices, use "RH" prefix instead of "IN", i.e. RH4896A instead of IN4896A.

NOTE 7 Consult factory for TX, TXV or JANS equivalent SCDs.

Noise Density (N_D) is specified in Microvolts-rms per square root cycle. Actual measurement is performed using a 1 to 3 KHz frequency bandpass at the Zener test current (I_{ZT}) @ 25°C ambient temperature.

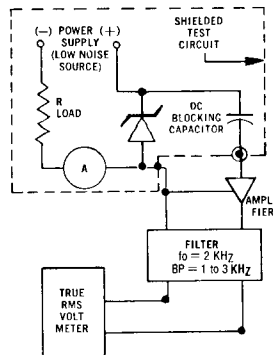


FIGURE 2 NOISE DENSITY MEASUREMENT CIRCUIT

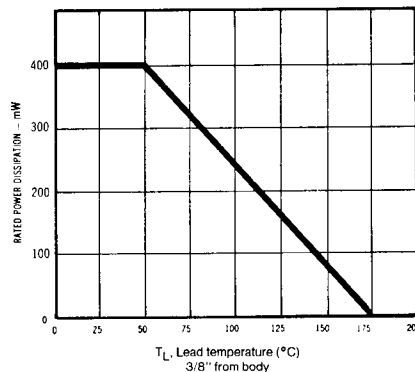


FIGURE 3 POWER DERATING CURVE

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Microsemi:

[1N4914A](#) [1N4901](#) [1N4900A](#) [1N4905A](#) [1N4902A](#) [1N4899A](#) [1N4908A](#) [1N4903A](#) [1N4904](#) [1N4906A](#) [1N4915](#)
[1N4913A](#) [1N4915A](#) [1N4912A](#) [1N4902](#) [1N4910](#) [1N4899](#) [1N4914](#) [1N4911A](#) [1N4911](#) [1N4909A](#) [1N4907](#) [1N4910A](#)
[1N4913](#) [1N4904A](#) [1N4896A](#) [1N4907A](#) [1N4897A](#) [1N4906](#) [1N4903](#) [1N4900](#) [1N4898A](#) [1N4901A](#) [1N4898](#)
[1N4908](#) [1N4909](#) [1N4896](#) [1N4897](#) [1N4905](#) [1N4912](#)